NSN 5961-00-137-4296

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-137-4296 **Inclosure Material:** Plastic **Overall Length:** 0.650 inches **Overall Height:** 0.520 inches **Overall Width:** 0.150 inches **End Application:** 8ticonderoga class c (47); nimitz class cvn; teletype, model 28; missile, air intercept, sidewinder (aim-9); forrestal class cv; los angeles class ssn (688); spruance class dd (963); landing craft air cushion (lcac); communications systems, an/wrr-7 **Mounting Facility Quantity:** 1 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 4.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp; weapon system essential **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig:

A110a0